General Purpose Transisters

PNP Silicon

Features

• Pb–Free Packages are Available

MAXIMUM RATINGS

Rating	Symbol	2907A	Unit
Collector-Emitter Voltage	V _{CEO}	-60	Vdc
Collector-Base Voltage	V _{CBO}	-60	Vdc
Emitter-Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current – Continuous	Ι _C	-600	mAdc

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T _A = 25°C Derate above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	–55 to +150	°C

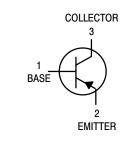
1. FR–5 = 1.0 \times 0.75 \times 0.062 in.

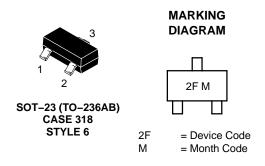
2. Alumina = 0.4 \times 0.3 \times 0.024 in. 99.5% alumina.



ON Semiconductor®

http://onsemi.com





ORDERING INFORMATION

Device	Package	Shipping [†]
MMBT2907ALT1	SOT-23	3000 Units/Reel
MMBT2907ALT1G	SOT-23 (Pb-Free)	3000 Units/Reel
MMBT2907ALT3	SOT-23	3000 Units/Reel
MMBT2907ALT3G	SOT-23 (Pb-Free)	3000 Units/Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Breakdown Voltage (Note 3) $(I_{C} = -10 \text{ mAdc}, I_{B} = 0)$		-60	-	Vdc
Collector – Base Breakdown Voltage $(I_C = -10 \ \mu Adc, I_E = 0)$	V _{(BR)CBO}	-60	_	Vdc
Emitter – Base Breakdown Voltage ($I_E = -10 \ \mu Adc, I_C = 0$)	V _{(BR)EBO}	-5.0	-	Vdc
Collector Cutoff Current ($V_{CE} = -30 \text{ Vdc}, V_{EB(off)} = -0.5 \text{ Vdc}$)	ICEX	_	-50	nAdc
Collector Cutoff Current $(V_{CB} = -50 \text{ Vdc}, I_E = 0)$ $(V_{CB} = -50 \text{ Vdc}, I_E = 0, T_A = 125^{\circ}\text{C})$	I _{CBO}	-	-0.010 -10	μAdc
Base Cutoff Current (V _{CE} = -30 Vdc, V _{EB(off)} = -0.5 Vdc)	I _{BL}	-	-50	nAdc
ON CHARACTERISTICS	•		•	
$ \begin{array}{l} \text{DC Current Gain} \\ (I_{C} = -0.1 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \\ (I_{C} = -1.0 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \\ (I_{C} = -10 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \\ (I_{C} = -150 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \\ (I_{C} = -500 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \\ (I_{C} = -500 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \\ (Note 3) \end{array} $	h _{FE}	75 100 100 100 50	- - 300 -	-
Collector – Emitter Saturation Voltage (Note 3) ($I_C = -150 \text{ mAdc}$, $I_B = -15 \text{ mAdc}$) (Note 3) ($I_C = -500 \text{ mAdc}$, $I_B = -50 \text{ mAdc}$)	V _{CE(sat)}	-	-0.4 -1.6	Vdc
Base – Emitter Saturation Voltage (Note 3) ($I_C = -150 \text{ mAdc}$, $I_B = -15 \text{ mAdc}$) ($I_C = -500 \text{ mAdc}$, $I_B = -50 \text{ mAdc}$)	V _{BE(sat)}		-1.3 -2.6	Vdc
SMALL-SIGNAL CHARACTERISTICS				
Current-Gain – Bandwidth Product (Notes 3, 4) ($I_C = -50$ mAdc, $V_{CE} = -20$ Vdc, f = 100 MHz)	fT	200	_	MHz

$(I_{C} = -50 \text{ mAdc}, V_{CE} = -20 \text{ Vdc}, t = 100 \text{ MHz})$		200	_	
Output Capacitance (V _{CB} = -10 Vdc, I _E = 0, f = 1.0 MHz)	C _{obo}	-	8.0	pF
Input Capacitance ($V_{EB} = -2.0 \text{ Vdc}, I_C = 0, f = 1.0 \text{ MHz}$)	C _{ibo}	-	30	

SWITCHING CHARACTERISTICS

Turn–On Time		t _{on}	-	45	
Delay Time	$(V_{CC} = -30 \text{ Vdc}, I_C = -150 \text{ mAdc}, I_{B1} = -15 \text{ mAdc})$	t _d	-	10	
Rise Time		tr	-	40	
Turn–Off Time		t _{off}	-	100	ns
Storage Time	$(V_{CC} = -6.0 \text{ Vdc}, I_C = -150 \text{ mAdc}, I_{B1} = I_{B2} = -15 \text{ mAdc})$	ts	-	80	
Fall Time		t _f	-	30]

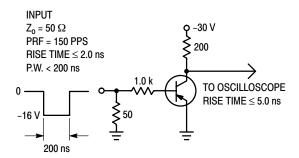


Figure 1. Delay and Rise Time Test Circuit

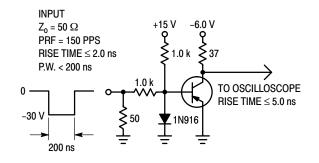
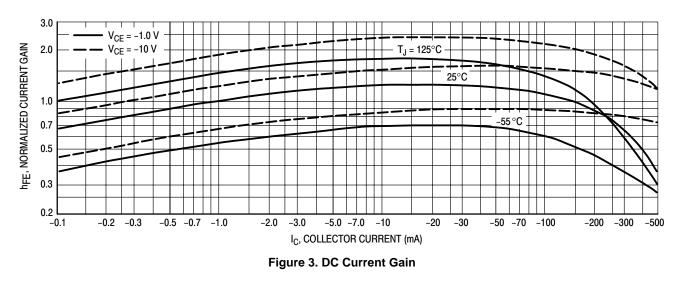
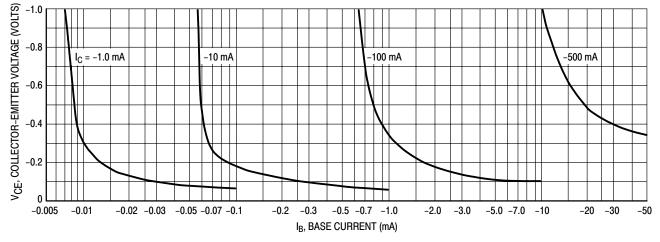


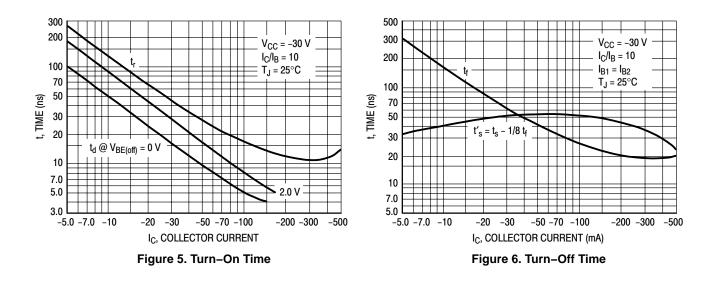
Figure 2. Storage and Fall Time Test Circuit

TYPICAL CHARACTERISTICS



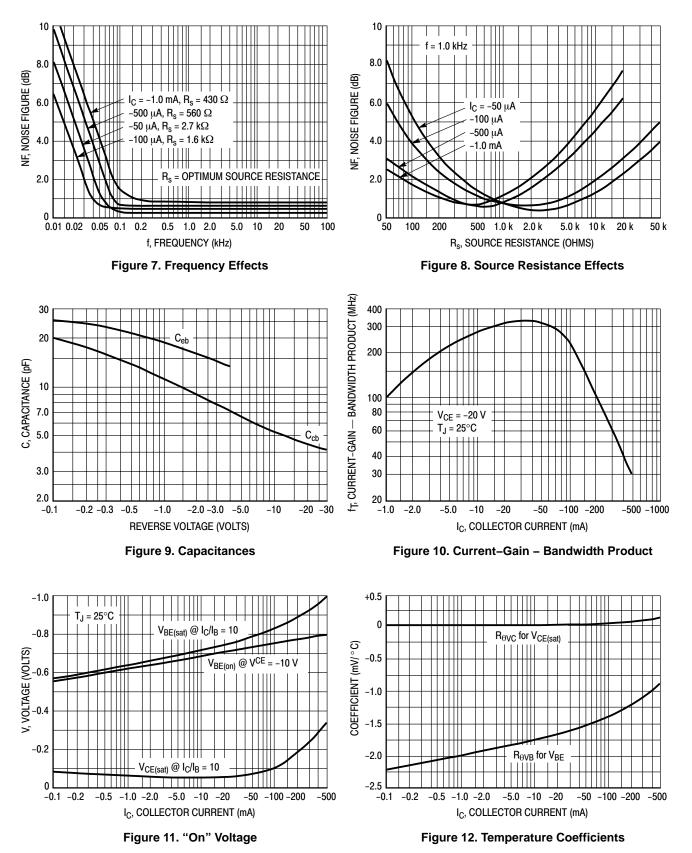






TYPICAL SMALL-SIGNAL Characteristics NOISE FIGURE

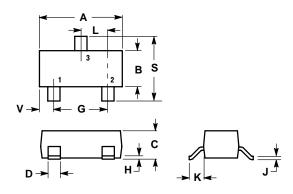
 V_{CE} = 10 Vdc, T_A = 25°C



PACKAGE DIMENSIONS

SOT-23 (TO-236AB) CASE 318-08

ISSUE AK



NOTES:

DIMENSIONING AND TOLERANCING PER 1. ANSI Y14.5M, 1982.

CONTROLLING DIMENSION: INCH.
MAXIMUM LEAD THICKNESS INCLUDES

LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF

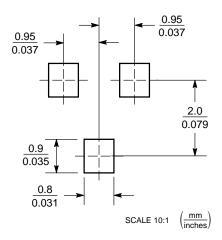
BASE MATERIAL. 4. 318–01 THRU –07 AND –09 OBSOLETE, NEW STANDARD 318-08.

	INC	CHES MILLIMETER		ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.1102	0.1197	2.80	3.04
В	0.0472	0.0551	1.20	1.40
С	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
н	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
к	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
s	0.0830	0.1039	2.10	2.64
v	0.0177	0.0236	0.45	0.60

STYLE 6:

PIN 1. BASE 2 FMITTER 3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and in the registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 61312, Phoenix, Arizona 85082-1312 USA Phone: 480-829-7710 or 800-344-3860 Toll Free USA/Canada Fax: 480-829-7709 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800–282–9855 Toll Free USA/Canada

Japan: ON Semiconductor, Japan Customer Focus Center 2-9-1 Kamimeguro, Meguro-ku, Tokyo, Japan 153-0051 Phone: 81-3-5773-3850

ON Semiconductor Website: http://onsemi.com

Order Literature: http://www.onsemi.com/litorder

For additional information, please contact your local Sales Representative.